

USR Semiconductor Co., Ltd

SYMBOL	CHARACTERISTIC	TEST CONDITIONS	T_j (°C)	VALUE			UNIT
				Min	Type	Max	
$I_{F(AV)}$	Mean forward current	180° half sine wave 50Hz single side cooled, $T_{hs}=55^\circ C$	150			445	A
$I_{F(AV)}$	Mean forward current	180° half sine wave 50Hz single side cooled, $T_{hs}=90^\circ C$	150			324	A
V_{RRM}	Repetitive peak reverse voltage	V_{RRM} tp=10ms $V_{RsM} = V_{RRM} + 100V$	150	100		2000	V
I_{RRM}	Repetitive peak current	at V_{RRM}	150			30	mA
I_{FSM}	Surge forward current	10ms half sine wave	150			4	KA
I^2T	I^2T for fusing coordination	$V_R=0.6V_{RRM}$				80	$A^2s \times 10^3$
V_{FO}	Threshold voltage		150			0.98	V
r_F	Forward slop resistance					0.88	$m\Omega$
V_{FM}	Peak on-state voltage	$I_{TM}=900A$	150			2.0	V
I_{rm}	Reverse recovery current					60	A
t_{rr}	Reverse recovery time	$I_{TM}=300A, tp=1000\mu s, di/dt=-20A/\mu s, V_R=50V$	150			4.0	μs
Q_{rr}	Recovery charge					120	μC
$R_{th(j-h)}$	Thermal resistance Junction to heatsink	At 180° sine single side cooled Clamping torque 27 N·m				0.11	$^\circ C /W$
F_m	Mounting torque			25		30	N·m
T_{stg}	Stored temperature			-40		160	$^\circ C$
Outline				D4			

Outline

